

Provisional Data

Rectifier Diode

Type W4713H#300 to W4713H#350

(Development Part No. Wx207H#300-350)

Absolute Maximum Ratings

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
V_{RRM}	Repetitive peak reverse voltage, (note 1)	3000-3500	V
V_{RSM}	Non-repetitive peak reverse voltage, (note 1)	3100-3600	V

	OTHER RATINGS	MAXIMUM LIMITS	UNITS
$I_{F(AV)M}$	Maximum average forward current, $T_{sink}=55^{\circ}C$, (note 2)	4713	A
$I_{F(AV)M}$	Maximum average forward current, $T_{sink}=100^{\circ}C$, (note 2)	3261	A
$I_{F(AV)M}$	Maximum average forward current, $T_{sink}=100^{\circ}C$, (note 3)	1996	A
$I_{F(RMS)M}$	Nominal RMS forward current, $T_{sink}=25^{\circ}C$, (note 2)	8678	A
$I_{F(d.c.)}$	D.C. forward current, $T_{sink}=25^{\circ}C$, (note 4)	7562	A
I_{FSM}	Peak non-repetitive surge $t_p=10ms$, $V_{rm}=60\%V_{RRM}$, (note 5)	56.0	kA
I_{FSM2}	Peak non-repetitive surge $t_p=10ms$, $V_{rm}\leq 10V$, (note 5)	61.6	kA
I^2t	I^2t capacity for fusing $t_p=10ms$, $V_{rm}=60\%V_{RRM}$, (note 5)	15.7×10^6	A^2s
I^2t	I^2t capacity for fusing $t_p=10ms$, $V_{rm}\leq 10V$, (note 5)	19.0×10^6	A^2s
$T_{j op}$	Operating temperature range	-40 to +160	$^{\circ}C$
T_{stg}	Storage temperature range	-40 to +160	$^{\circ}C$

Notes:-

- 1) De-rating factor of 0.13% per $^{\circ}C$ is applicable for T_j below $25^{\circ}C$.
- 2) Double side cooled, single phase; 50Hz, 180° half-sinewave.
- 3) Single side cooled, single phase; 50Hz, 180° half-sinewave.
- 4) Double side cooled.
- 5) Half-sinewave, $160^{\circ}C$ T_j initial.

Characteristics

	PARAMETER	MIN.	TYP.	MAX.	TEST CONDITIONS (Note 1)	UNITS
V_{FM}	Maximum peak forward voltage	-	-	1.35 1.50	$I_{TM}=6000A$ $I_{TM}=8000A$	V
V_{T0}	Threshold voltage	-	-	0.807	Range 2000A – 6000A	V
r_T	Slope resistance	-	-	0.09		mΩ
I_{RRM}	Peak reverse current	-	-	150 150	Rated V_{RRM} Rated V_{RRM} , $T_J=25^{\circ}C$	mA
Q_{rr}	Recovered charge	-	7500	8600	$I_{TM}=2000A$, $t_p=2000\mu s$, $di/dt=10A/\mu s$, $V_r=100V$	μC
Q_{ra}	Recovered charge, 50% chord	-	6000	-		μC
I_{rm}	Reverse recovery current	-	250	-		A
t_{rr}	Reverse recovery time, 50% chord	-	47	-		μs
R_{thJK}	Thermal resistance, junction to heatsink	-	-	0.012 0.024	Double side cooled Single side cooled	K/W
F	Mounting force	36	-	44		kN
W_t	Weight	-	1.2 1.5	-	Outline option HL Outline option HM	kg

Notes:-

1) Unless otherwise indicated $T_J=160^{\circ}C$.

Notes on Ratings and Characteristics**1.0 Voltage Grade Table**

Voltage Grade	V_{RRM} V	V_{RSM} V	V_R DC V
30	3000	3100	1700
32	3200	3300	1800
34	3400	3500	1850
35	3500	3600	1875

2.0 Extension of Voltage Grades

This report is applicable to other voltage grades when supply has been agreed by Sales/Production.

3.0 De-rating Factor

A blocking voltage de-rating factor of 0.13%/°C is applicable to this device for T_j below 25°C.

4.0 Snubber Components

When selecting snubber components, care must be taken not to use excessively large values of snubber capacitor or excessively small values of snubber resistor. Such excessive component values may lead to device damage due to the large resultant values of snubber discharge current. If required, please consult the factory for assistance.

5.0 Computer Modelling Parameters**5.1 Device Dissipation Calculations**

$$I_{AV} = \frac{-V_{T0} + \sqrt{V_{T0}^2 + 4 \cdot ff^2 \cdot r_T \cdot W_{AV}}}{2 \cdot ff^2 \cdot r_T} \quad \text{and:} \quad W_{AV} = \frac{\Delta T}{R_{th}}$$

$$\Delta T = T_{j\max} - T_K$$

Where $V_{T0}=0.807V$, $r_s=0.09m\Omega$,

R_{th} = Supplementary thermal impedance, see table below and

ff = Form factor, see table below.

Supplementary Thermal Impedance				
Conduction Angle	6 phase (60°)	3 phase (120°)	½ wave (180°)	d.c.
Square wave Double Side Cooled	0.0138	0.0132	0.0128	0.012
Square wave Single Side Cooled	0.0262	0.0255	0.0250	0.024
Sine wave Double Side Cooled	0.0134	0.0129	0.0123	
Sine wave Single Side Cooled	0.0257	0.0251	0.0244	

Form Factors				
Conduction Angle	6 phase (60°)	3 phase (120°)	½ wave (180°)	d.c.
Square wave	2.449	1.732	1.414	1
Sine wave	2.778	1.879	1.57	

5.2 Calculating V_F using ABCD Coefficients

The on-state characteristic I_F vs. V_F , on page 5 is represented in two ways;

- (i) the well established V_0 and r_s tangent used for rating purposes and
- (ii) a set of constants A, B, C, D, forming the coefficients of the representative equation for V_F in terms of I_F given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

The constants, derived by curve fitting software, are given below for both hot and cold characteristics. The resulting values for V_F agree with the true device characteristic over a current range, which is limited to that plotted.

25°C Coefficients		160°C Coefficients	
A	0.691735365	A	0.489564365
B	0.029196	B	0.025175
C	3.500000E ⁻⁰⁵	C	4.300000E ⁻⁰⁵
D	2.664000E ⁻⁰³	D	4.950000E ⁻⁰³

5.3 D.C. Thermal Impedance Calculation

$$r_t = \sum_{p=1}^{p=n} r_p \cdot \left(1 - e^{\frac{-t}{\tau_p}} \right)$$

Where $p = 1$ to n , n is the number of terms in the series and:

t = Duration of heating pulse in seconds.

r_t = Thermal resistance at time t .

r_p = Amplitude of p_{th} term.

τ_p = Time Constant of r_{th} term.

The coefficients for this device are shown in the tables below:

D.C. Double Side Cooled				
Term	1	2	3	4
r_p	5.70694×10^{-3}	4.354047×10^{-3}	1.146543×10^{-3}	8.138617×10^{-4}
τ_p	1.486448	0.2518236	0.07993583	5.569284×10^{-3}

D.C. Single Side Cooled				
Term	1	2	3	4
r_p	0.0162195	5.732856×10^{-3}	1.48536×10^{-3}	7.633434×10^{-4}
τ_p	8.431941	0.3637194	0.0701921	4.56943×10^{-3}

Curves

Figure 1 – Forward characteristics of Limit device

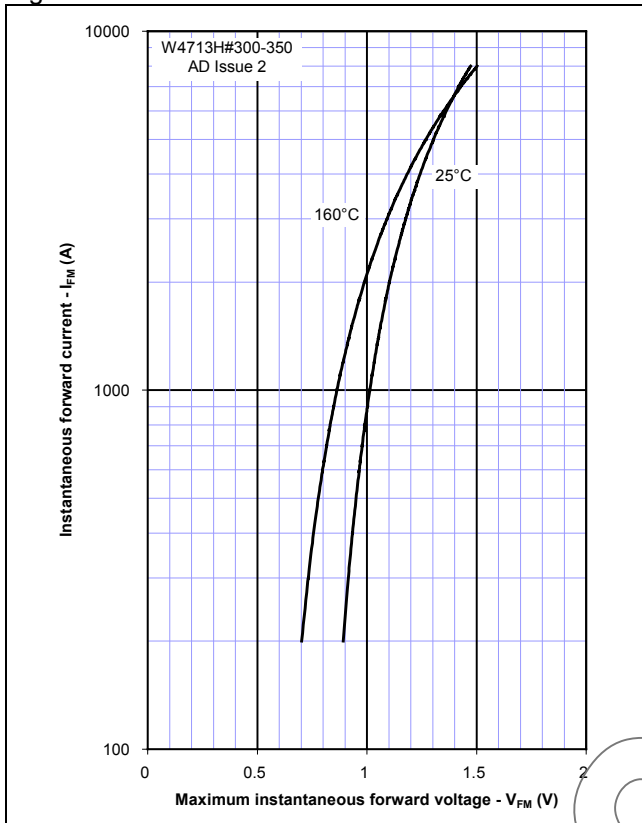


Figure 2 – Transient thermal impedance

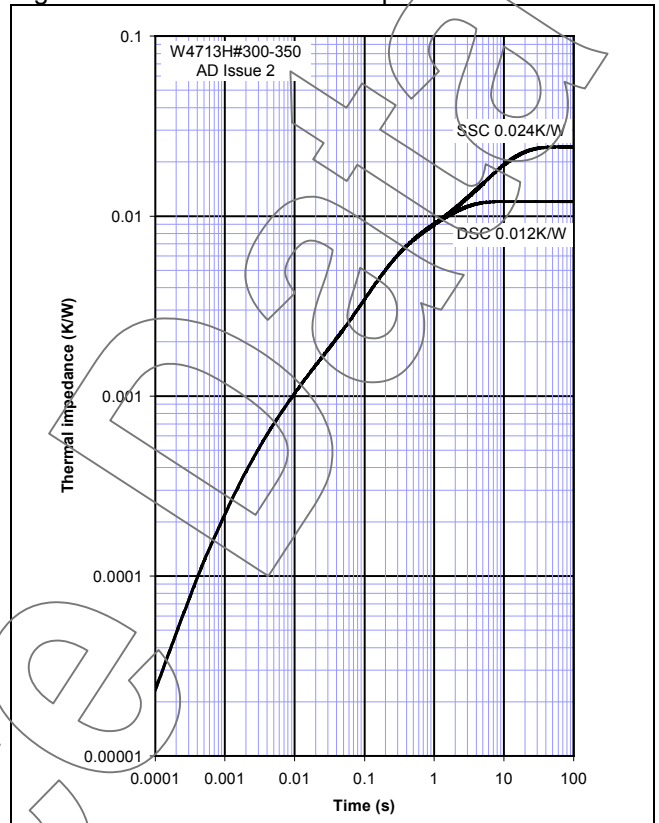


Figure 3 – Maximum surge Rating

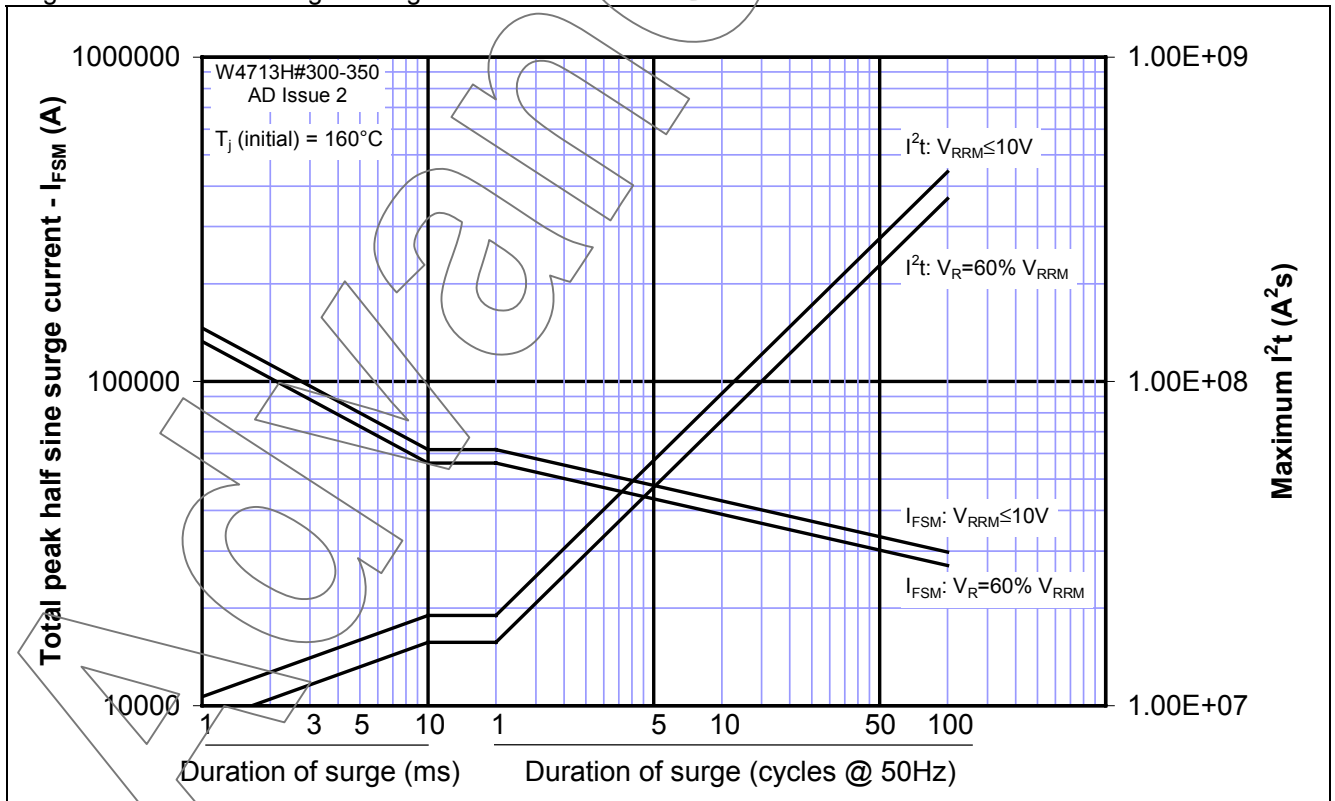


Figure 4 – Total recovered charge, Q_{rr}

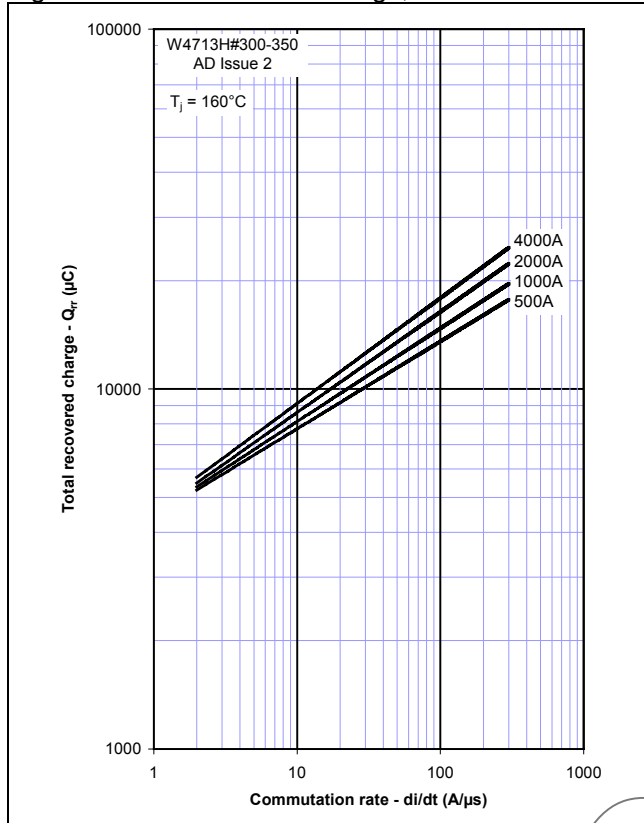


Figure 5 – Recovered charge, Q_{ra} (50% Chord)

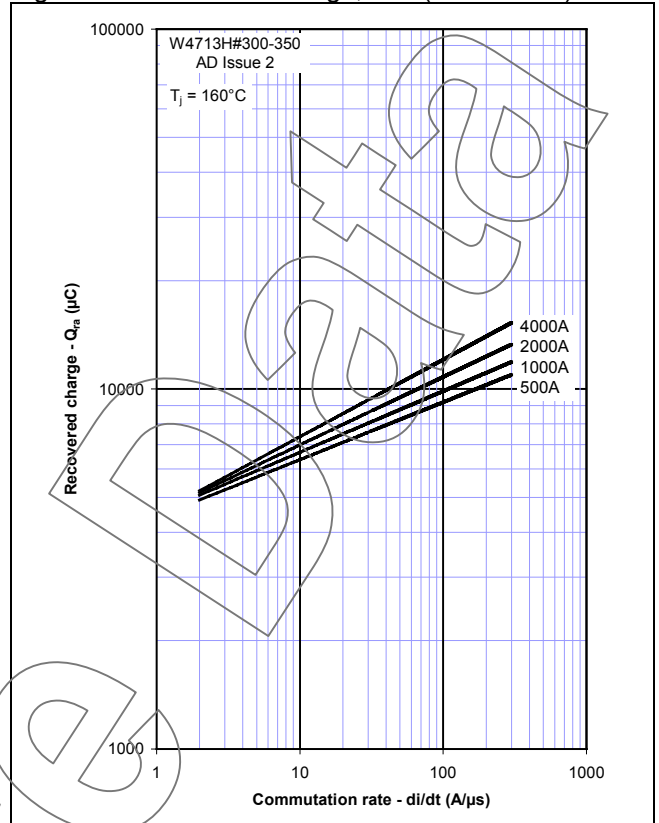


Figure 6 – Peak recovery current, I_{rr}

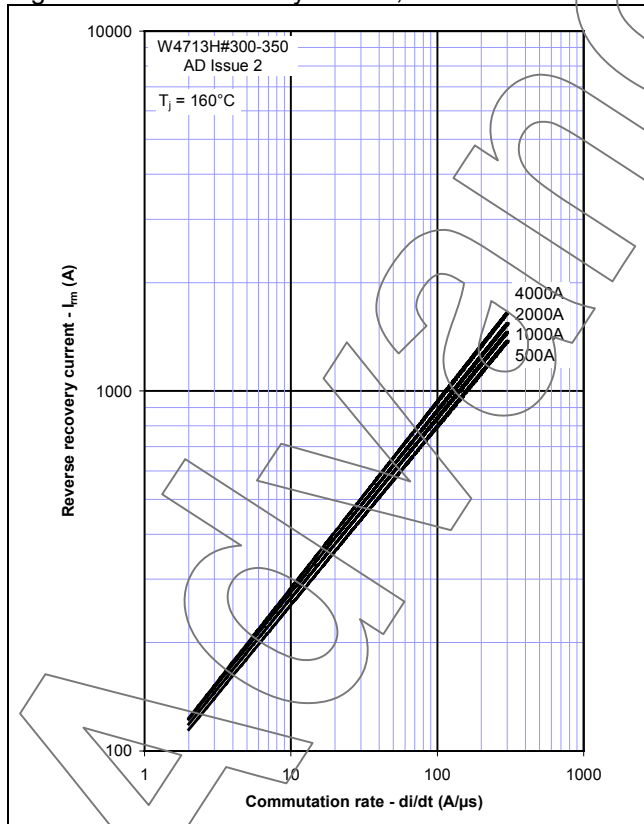


Figure 7 – Maximum recovery time, t_{rr} (50% Chord)

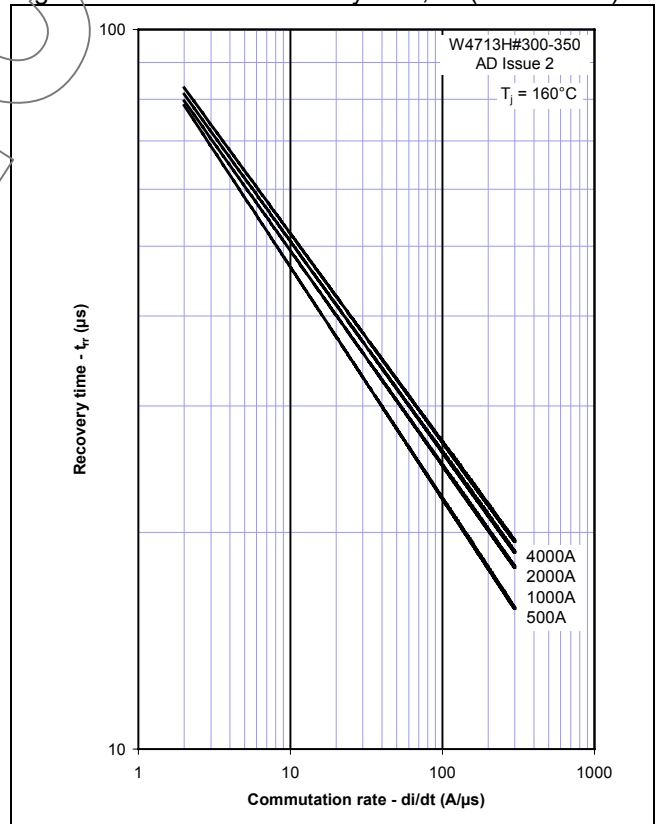


Figure 8 – Forward current vs. Power dissipation – Double Side Cooled

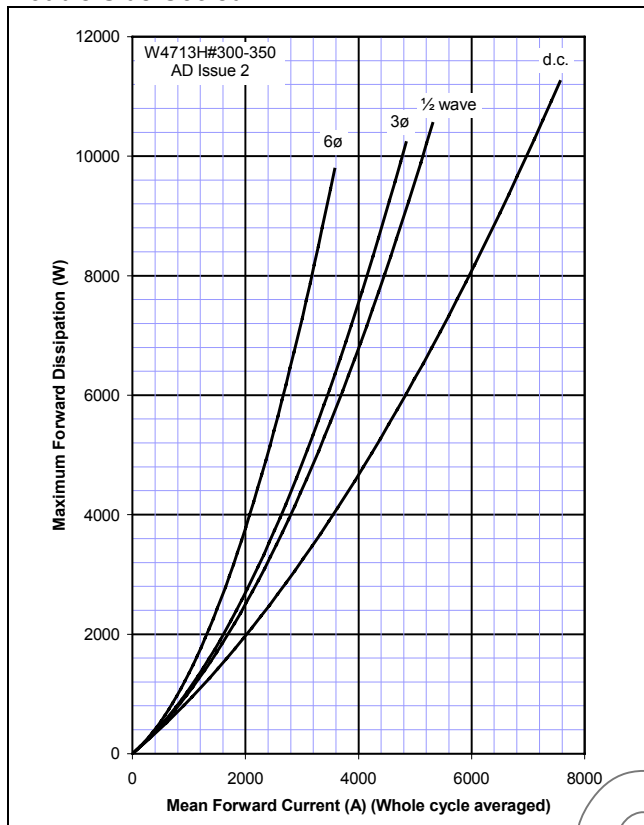


Figure 9 – Forward current vs. Heatsink temperature - Double Side Cooled

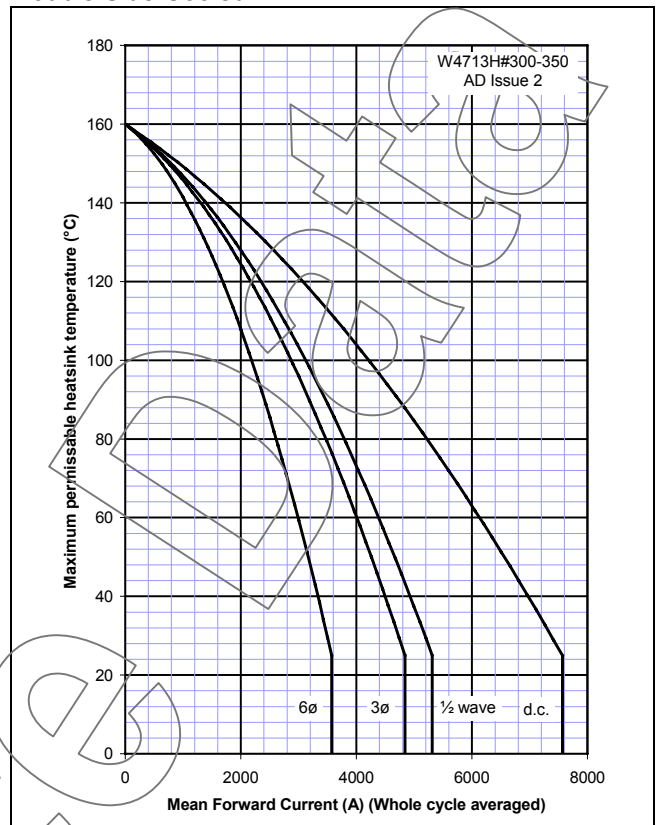


Figure 10 – Forward current vs. Power dissipation – Single Side Cooled

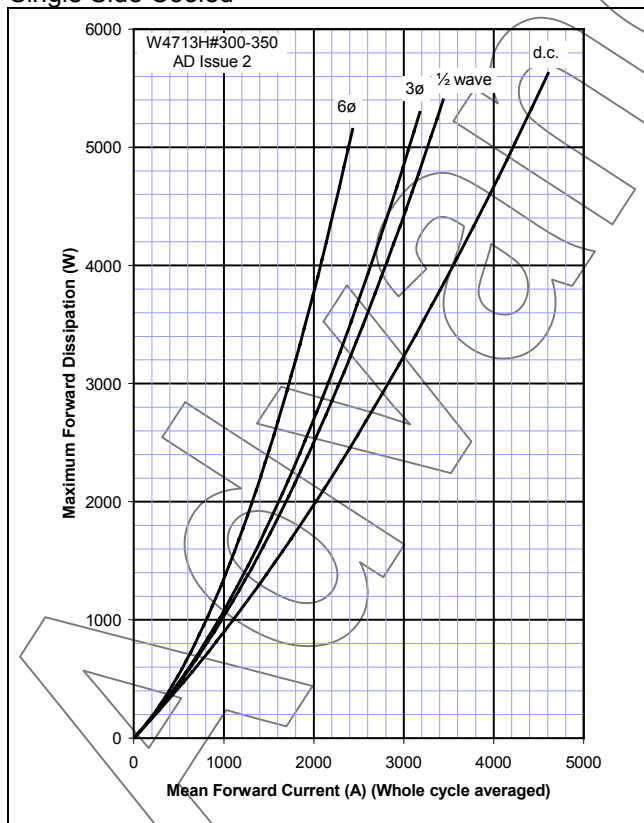
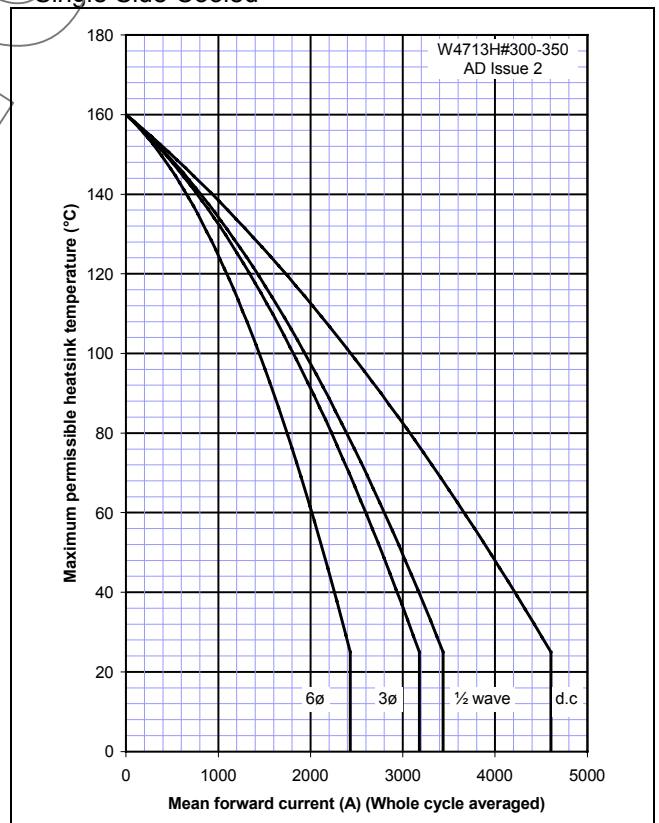
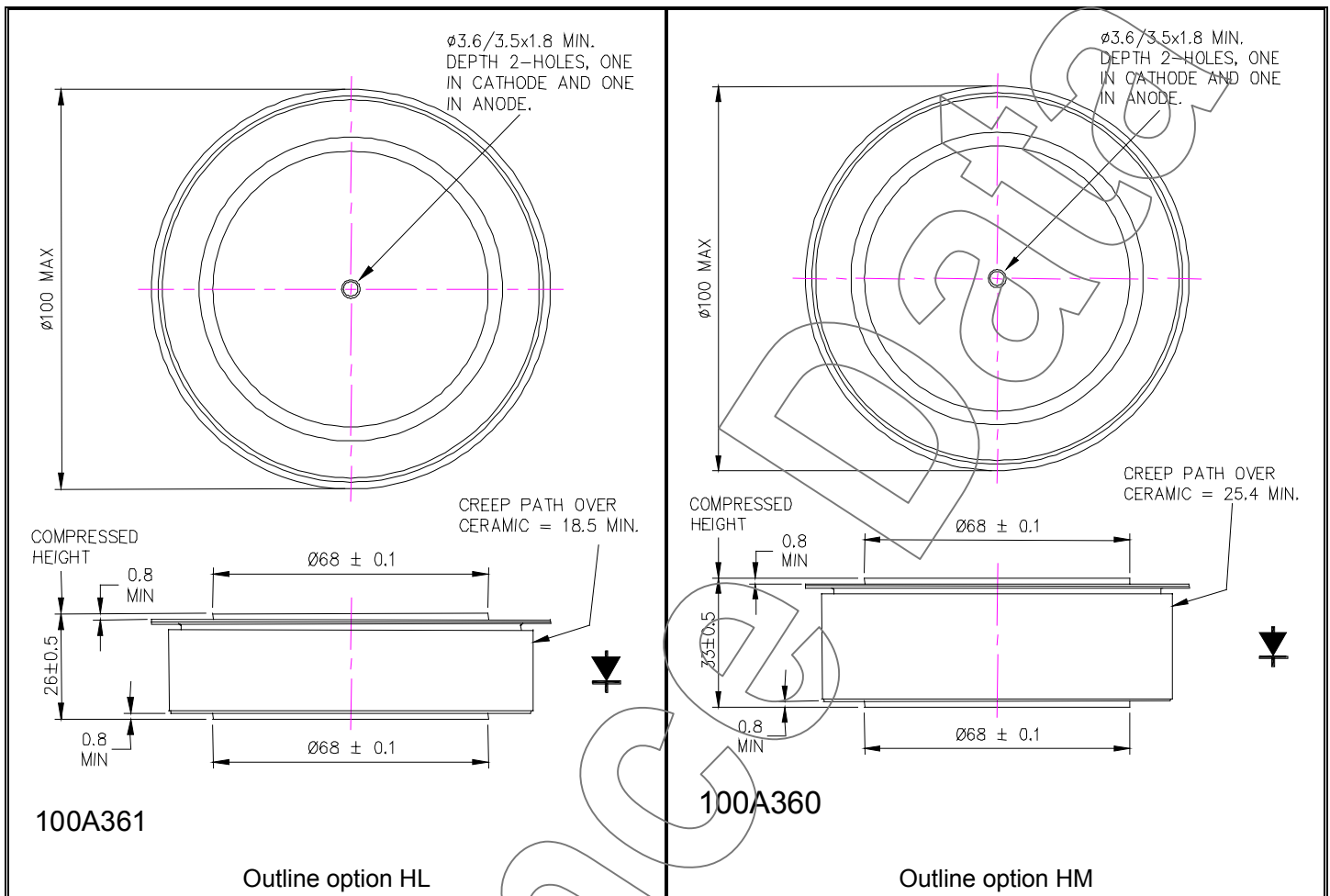


Figure 11 – Forward current vs. Heatsink temperature – Single Side Cooled



Outline Drawing & Ordering Information



ORDERING INFORMATION

(Please quote 10 digit code as below)

W4713	H#	◆◆	0
Fixed Type Code	Fixed outline code HL = 26mm Clamp height HM = 33mm Clamp height	Voltage code $V_{RRM}/100$ 30-35	Fixed code

Typical order code: W4713HL340 – 3400V V_{RRM} , 26mm clamp height capsule.

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